

Preparation of Hybrid Junction Light Emitting Device from Cadmium Sulphite Quantum dot/ poly-TPD Junction

Hussein Riyadh Mohammed
Department of Physics, College of Science, University of
Baghdad, Baghdad, Iraq
husseini6762@gmail.com

Omar A. Ibrahim
Department of Physics, College of Science, University of
Baghdad, Baghdad, Iraq
omaradnanphy@gmail.com

Abstract— Stratus of ITO/TPD:PMMA/CdS/Alq3/Al were used to make the hybrid nanoparticles light emitting diode (NPs-LED), which were created using the phase segregation method and the spin coating procedure. Light-generating NPs-LED hybrid device is composed of 3 stratus stacked in a certain order on an Indium tin oxide (ITO) substrate made of transparent conducting oxide. The first stratum was (N, N'-bis (3-methylphenyl)-N, N'-bis (phenyl) benzidine) (TPD) polymer, and polymethyl methacrylate (PMMA) polymer. Cadmium Sulphite (CdS) is the second stratum, while Tris (8-hydroxyquinolino) aluminum (Alq3) is the last stratum, which is one of the materials used as electron injector stratus.

Various bias voltages (28, 30, and 32V) were used to examine the electroluminescence (EL) of NPs-LEDs at room temperature, depending on the CIE 1931 color spaces, light was created at 32V, whereas blue light was generated at 28V. The transmission between sub levels in the energy gap of CdS NPs (surface state). Voltages are controlling the current change, and the knee voltage is 6.6 V, as seen by the current – voltage (I-V) distinctive. EL spectrum demonstrates a broadband emission spanning 300 nm to 700 nm. Finally, it is discovered that the correlated color temperature (CCT) is about (7450 to 11820k).

Keywords— Cadmium Sulphite, Nanoparticle, electroluminescence, LED

I. INTRODUCTION

Quantum dots are of incredible logical interest as they are an extension between bulk materials and nuclear or atomic constructions. A bulk material ought to have constant physical properties as per its size, since the nanoparticles have a large number of surface atoms compare with the bulk. Thus the distinctives of the surface atoms have more effect on the main physical and chemical properties of the material change it does not increase or decrease, but completely changes, At the nanoscale, the surface area increases relative to volume, and the material becomes more effective, thus, its reactive capacity increases, the electrical, optical and thermal properties change, thus increasing the energy gap with a decrease in size. Therefore, noticed that when entering Cadmium Sulphite (CdS) the nanoscale, the energy gap

increases, making its emissions within the blue light zone at 450nm after it was 520 nm in the bulk measurements[1].

The photoluminescence (PL) lifespan is in the range of 10-4 sec and the radiative recombination of departed electrons in C.B and holes in V.B is direct. CdS is an optoelectronic, piezoelectric, and semiconducting material with several applications. The efficient utilization of CdS thin films in the production of solar cells and the generation of white light is of great interest [2]. It has deep sub levels in CdS resulting from more defect states in the band gap, which can help to an emission band different colors that includes the entire visible spectrum [2, 3, 4]. As a result of this feature, In white LEDs, the CdS is employed [5]. The electrical and optical properties of the constructed heterostructure device will be unique due to the combination of Cadmium Sulphite nanoparticles pentavalent type with some organic and inorganic semiconductors trivalent type [6].

The development of a pn junction was the consequence of the incorporation of semiconductor nanoparticles into organic matrices electro-luminescence device. Placing dielectric nanoparticles in an OLED hybrid circuit has an effect on the luminescence spectra because the energy of the lowest unoccupied molecular orbital (LUMO) and the highest occupied molecular orbital (HOMO) are different (HOMO) Because the energy levels of the TPD polymer are close to those of the embedded semiconductor, energy transfer and electronic polarization of the environment will occur. CdS NPs were employed to create a TPD in this study: Study the EL and PL characteristics of PMMA: cds NP hybrid couplers utilizing spin coating. The phase segregation technique is used to obtain the light-emitting layers of the cds NPs. To produce a device based on CdS, this approach is an affordable and easy solution procedure that does not require specialized vacuum technique equipment [3,7].

II. EXPERIMENTAL WORK

Glass transparent sheet (ITO) is used as a substrate for stratus of the thin films are positioned when producing hybrid films comprised of organic and inorganic components. The (TPD) solution is made by dissolving 75

mg of (TPD) in one milliliter chloroform, and with a blend of TPD:PMMA, solutions TPD and PMMA were combined to produce a mixture, this mixture and NPs ratios are 1: 0.5 percent, respectively, cds was added to the mixture at a percentage of (X / 200) (TPD:PMMA). A magnetic stirrer and an ultrasonic route were used to make the combination (blend and NPs). After that, the movie is made. To make the initial layer of the device, we cleaned ITO and spun-coated the combination (blend and CdS) on it for 30 seconds at 2000 rpm, then dried it in the oven at 80 ° C for 2 hours[8]. At the same time, ethanol (insoluble solvent TPD) was used to dissolve (Alq3) (electron injection layer) in 75 mg: 3 ml. On the first stratum, this stratum is also deposited using the spin-coating process at 2000 rpm for 30s. The films were then baked for two hours at 60 degrees Celsius to remove any residual solvents. Finally, an aluminum contact was deposited as a negative cathode using the evaporation under 4*10⁻⁵ mbar pressure to produce the thin film (ITO/TPD: PMMA/ CdS/Alq3/Al) device.

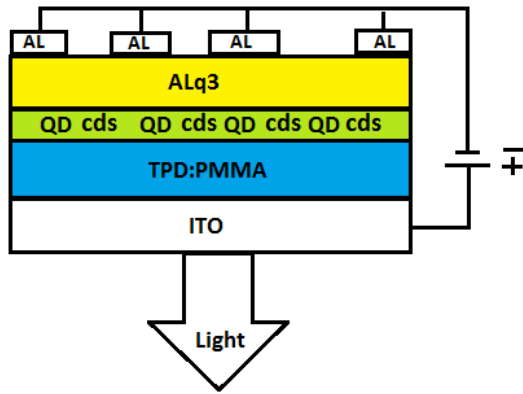


Fig 1: formation of thin film hybrid junction device for CdS NPS

The structure of the hybrid junction (TPD:PMMA/CdS NPs) device is shown in Fig 1. CdS nanoparticles on the organic mix layer due to phase segregation technique. The device's structure is made up of three stratum that are retained sequentially on ITO base stratum by phase segregation using the spin-coating method. The most widely used is indium oxide and tin (ITO). Other simple conductive oxides are included in the selections. The TPD's natural stratum is a hole injector film, whereas, CdS NPs and Alq3 are electron injector stratum. Because the viscosity of NPs in chloroform differs from that of the mix (TPD: PMMA), the phase segregation method was employed to separate them by spin-coating.

III. RESULTS AND DISCUSSIONS

A. Electrical mensuration:

In Fig (3), the current-voltage (I-V) distinctive of thin film the hybrid junction device as capable of the predisposition voltage at room temperature are shown.

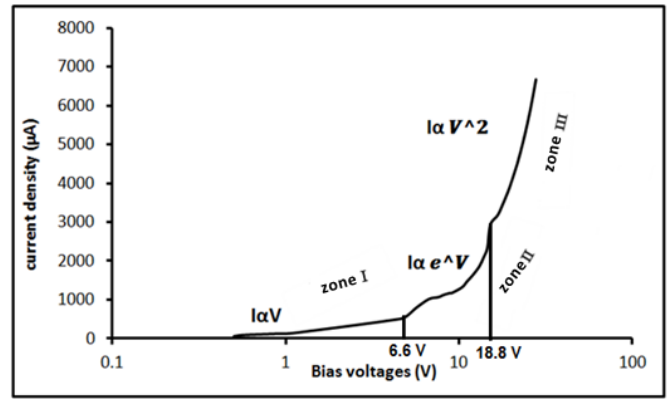


Fig.(3): The Current-voltage (I-V) distinctive for thin film hybrid junction device

Standard thermionic emission theory[8] was used to investigate I-V distinctive of the thin film hybrid junction device. These findings show that the current transfer mechanism may be found in three distinct zones. In the zone (I) (6.6 V), the current density follows a straight linear connection (Ohmic relationship) (IV). This shows that the present transportation system is inefficient. Tunneling dominates current transfer at low voltages [9]. This zone's border was established under threshold voltage (6.6V). The current density grows exponentially as ($I \propto e^V$) in the zone (II) (18.8 V). A thermionic process flowing through the obstacle produces carriers that are introduced into the dielectric. As a result, the number of free charges is fewer than the ratio of trapped to captured charges. It also exhibits the exponential voltage dependency [10], where the injected carriers rapidly grow and the traps are filled (defect stated) [2] at 18.8V, which is known as the Traps-Filled-Limit Voltage (VTFL).

The current density obeys a power law ($I \propto V^2$) above 18.8V (zone III), and the light discharge begins at zone (III), in 20V and 610A, due to the fact that the transport through the ITO/TPD: PMMA/ CdS/Alq3/Al Trap-Charge Limited Current (TCLC) in the hole of the CdS NPs drives the hybrid stratum. This implies that the density of injected charge carriers is more essential than the density of free charge carriers supplied thermally. The charge carrier transport dominated by space-charge limited current (SCLC) [11].

The I-V is distinctives of the three samples indicate that decreasing the depletion layer thickness at the interface causes an exponential rise in current. Due to the exponential distribution of electrons and holes within the C.B and V.B, the conduction band barrier is reduced under forward bias, and the diffusion carriers flowing through the junction rises exponentially. with increasing forwarding bias, exponentially The electron flow from the n-(NPs) to the p-(TPD) and holes flow from the p-(TPD) to the n-(NPs) will be enhanced by the drift current flowing in the opposite direction, which is independent of the potential barrier height (NPs). The forward bias current flow would result from consecutive recombination. This means that as the forward bias voltage is increased, the diode resistance decreases first (i.e., the reduced barrier potential). Figure 3 shows of the I-V data at R.T, which shows that the influx transport mechanism is shown in 3 distinct zones.

B. Electro-luminescence mensuration:

Estimates of electro-luminescence at front bias voltages of (28,30,32 V) point to the possibility of light obtained provisionally through us thin film hybrid junction devices, hybrid junction devices were done it at room temperature employing a photomultiplier detector. In this hybrid coupling device, the carrier's transport component is the TPD, which acts as a hole injected stratum, As an electron injected stratum, Alq3 is used. ITO anode in the HOMO of the terminal potential difference connection creates the gaps. It is then sent to VB or the Charge Transfer (CT) of CdS. Meanwhile, electrons are injected into the Alq3 LOMO networks at the cathode and transported to the conduction band (CB) the state of the CT and the evidence of imperfection of the CdS [2] CT, as seen in Fig (5). Inter band recombination is the process through which holes and electrons in CdS NPs recombine to form excitons. Through the recombination of holes and electrons through defects, light of various wavelengths is produced. Recombination is a process that involves the recombination of two or more genes. Shockley-Reed-Hall recombination [12, 13] is a kind of recombination caused by defects.

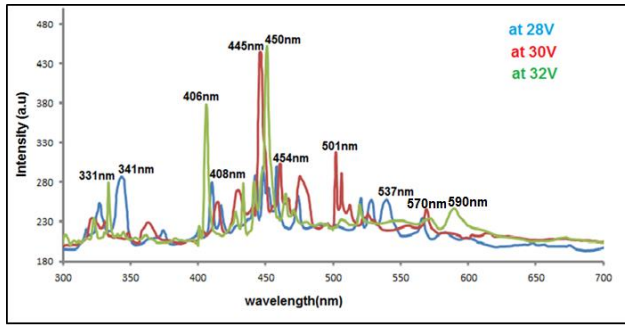


Fig. (4): EL of (TPD:PMMA)/CdS/Alq3 at different voltages

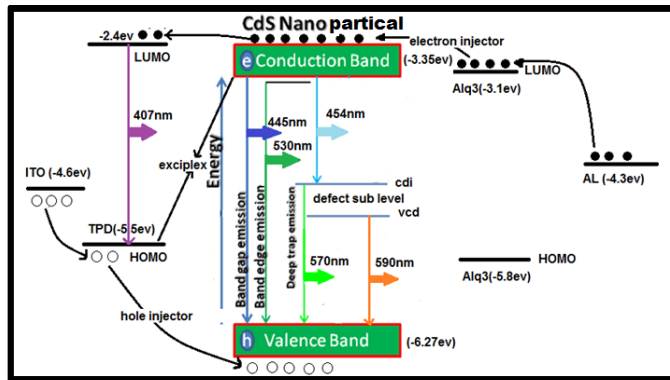


Fig. (5): Energy bands schema of ITO/(TPD: PMMA)/CdS/Alq3/Al hybrid device [3,4 , 14,15 and 16]

Because EL devices have sub-10nm spacing between TPD and CdS NPs, irritations out of nan-radiative vitality pass through polymer hole injector to CdS nanoparticles [18]. Blue emission 445- 454 nm, Green emission 501-537nm and orange emissions 570 – 590 nm corresponds to transitions resulting from defects in CdS or surface state in nanoparticles effect to V.B of CdS. Every one of these

advancements may be seen in graph (5). The color spaces CIE 1931 Chromaticity Coordinate Fig(6) determine the shade of light. It means that X , Y & Z are used to get the x and y values.

$$x = \frac{X}{X + Y + Z} \dots \dots \dots (1)$$

$$y = \frac{Y}{X + Y + Z} \dots \dots \dots (2)$$

Where all three locations(X,Y,Z) are zones beneath the bend for red, green and blue (RGB) districts, respectively, in the EL range. McCamy's formula can be used to determine the correlated color temperature (cct).

Eq. 3 shows the associated color temperature with the usage of χ and γ chromaticity [15]:

$$CCT = -449n^3 + 3525n^2 - 6823n + 5520.33 - \dots (3)$$

where n equals to,

$$n = (x - 0.332)/(y - 0.1855)$$

List (2) shows the values of χ , γ and CCT.

Table (2): CCT and χ , γ coordination for Multiple voltages

specimen	Voltage	χ , γ	CCT(K ⁰)
ITO/TPD:PMMA/ CdS/Alq3/Al	28	0.168 , 0.43	11820 K ⁰
	30	0.3 , 0.327	7250 K ⁰
	32	0.206 , 0.29	7450 K ⁰

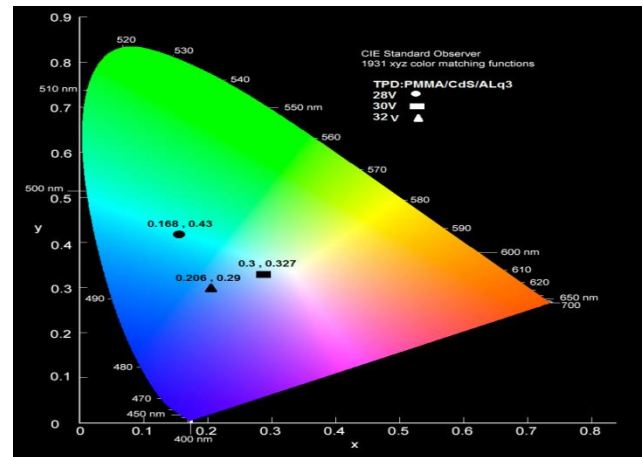


Fig.(6) : schema the correlated color temperature (CCT) for (TPD: PMMA)/CdS/Alq3 hybrid junction device

IV. CONCLUSION

In summary, we demonstrated that by controlling the bias voltage, organic-inorganic mongrel composites generate blue ,green and orange light, transitioning between the sub levels in the Eg of CdS NPs and defect states of the CdS nanoparticles. The increased quantity of transmission

through the sub levels of CdS is linked to the creation of white light.

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